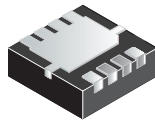




**THE DATASHEET OF
CSD25401Q3**





P-Channel NexFET™ Power MOSFETs

Check for Samples: [CSD25401Q3](#)

FEATURES

- Ultra Low Q_g and Q_{gd}
- Low Thermal Resistance
- Low $R_{DS(on)}$
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 3.3mm x 3.3mm Plastic Package

APPLICATIONS

- DC-DC Converters
- Battery Management
- Load Switch
- Battery Protection

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion load management applications. The SON 3x3 package offers excellent thermal performance for the size of the package.

Table 1. PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	-20	V
Q_g	Gate Charge Total (4.5V)	8.8	nC
Q_{gd}	Gate Charge Gate to Drain	2.1	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = -2.5V$	13.5 mΩ
		$V_{GS} = -4.5V$	8.8 mΩ
V_{th}	Threshold Voltage	-0.85	V

ORDERING INFORMATION

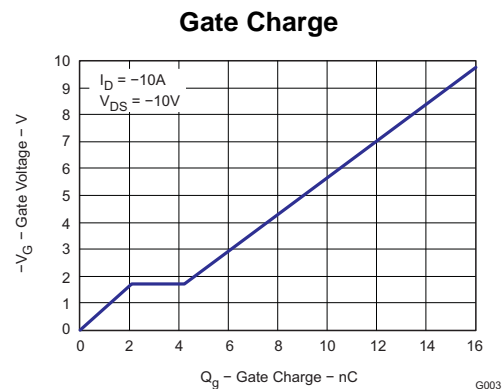
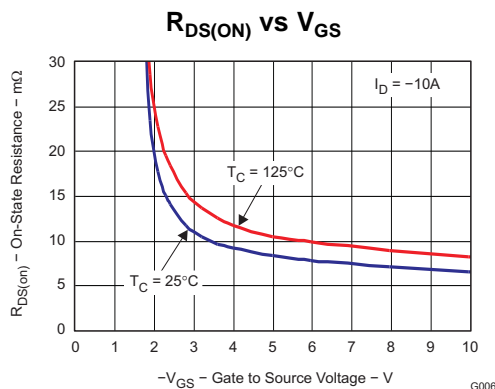
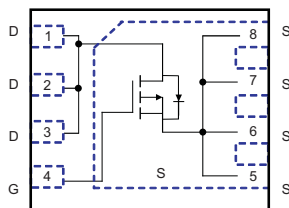
Device	Package	Media	Qty	Ship
CSD25401Q3	SON 3 x 3 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain to Source Voltage	-20	V
V_{GS}	Gate to Source Voltage	+12 / -12	V
I_D	Continuous Drain Current, $T_C = 25^\circ\text{C}$	-60	A
	Continuous Drain Current ⁽¹⁾	-14	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾	-82	A
P_D	Power Dissipation ⁽¹⁾	2.8	W
T_J , T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

- (1) $R_{\theta JA} = 45^\circ\text{C/W}$ on 1inch² Cu (2 oz.) on 0.060" thick FR4 PCB.
- (2) Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$

Figure 1. Top View



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ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

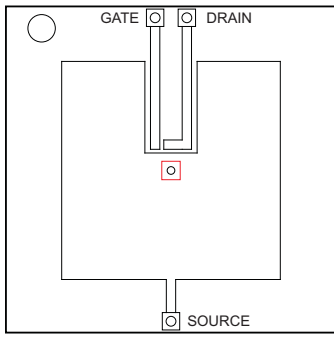
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
B _V DSS	Drain to Source Voltage	V _{GS} = 0V, I _D = -250μA	-20			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = -20V to -16V			-1	μA
I _{GSS}	Gate to Source Leakage Current	V _{DS} = 0V, V _{GS} = ±12V			-100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	V _{DS} = V _{GS} , I _D = -250μA	-0.6	-0.85	-1.2	V
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = -2.5V, I _D = -10A		13.5	18.2	mΩ
		V _{GS} = -4.5V, I _D = -10A		8.8	11.7	mΩ
g _{fs}	Transconductance	V _{DS} = -15V, I _D = -10A		43		S
Dynamic Characteristics						
C _{ISS}	Input Capacitance	V _{GS} = 0V, V _{DS} = -10V, f = 1MHz		1070	1400	pF
C _{OSS}	Output Capacitance			560	730	pF
C _{RSS}	Reverse Transfer Capacitance			180	230	pF
Q _g	Gate Charge Total (4.5V)	V _{DS} = -10V, I _D = -10A		8.8	12.3	nC
Q _{gd}	Gate Charge Gate to Drain			2.1		nC
Q _{gs}	Gate Charge Gate to Source			2.1		nC
Q _{g(th)}	Gate Charge at V _{th}			0.9		nC
Q _{OSS}	Output Charge	V _{DS} = -10V, V _{GS} = 0V		8.2		nC
t _{d(on)}	Turn On Delay Time	V _{DS} = -10V, V _{GS} = -4.5V, I _D = -10A, R _G = 5.1Ω		8.1		ns
t _r	Rise Time			3.9		ns
t _{d(off)}	Turn Off Delay Time			13.5		ns
t _f	Fall Time			12.6		ns
Diode Characteristics						
V _{SD}	Diode Forward Voltage	I _S = -10A, V _{GS} = 0V		-0.7	-1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = -12.5V, I _F = -10A, di/dt = 300A/μs		17.4		nC
t _{rr}	Reverse Recovery Time			21		ns

THERMAL INFORMATION

THERMAL METRIC ⁽¹⁾⁽²⁾		CSD25401Q3	UNITS
		8 PIN	
θ _{JA}	Junction-to-ambient thermal resistance	42.0	°C/W
θ _{JCtop}	Junction-to-case (top) thermal resistance	20.6	
θ _{JB}	Junction-to-board thermal resistance	8.8	
ψ _{JT}	Junction-to-top characterization parameter	0.3	
ψ _{JB}	Junction-to-board characterization parameter	8.7	
θ _{JCbot}	Junction-to-case (bottom) thermal resistance	0.1	

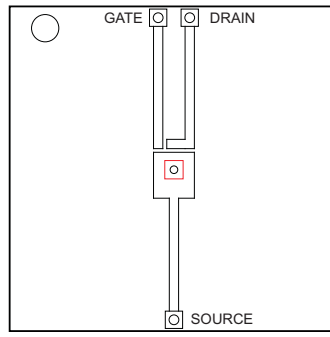
(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

(2) For thermal estimates of this device based on PCB copper area, see the [TI PCB Thermal Calculator](#).



M0137-01

Max $R_{\theta JA} = 57^{\circ}\text{C/W}$
when mounted on
 1inch^2 of 2 oz. Cu.



M0137-02

Max $R_{\theta JA} = 158^{\circ}\text{C/W}$
when mounted on
minimum pad area of 2
oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)

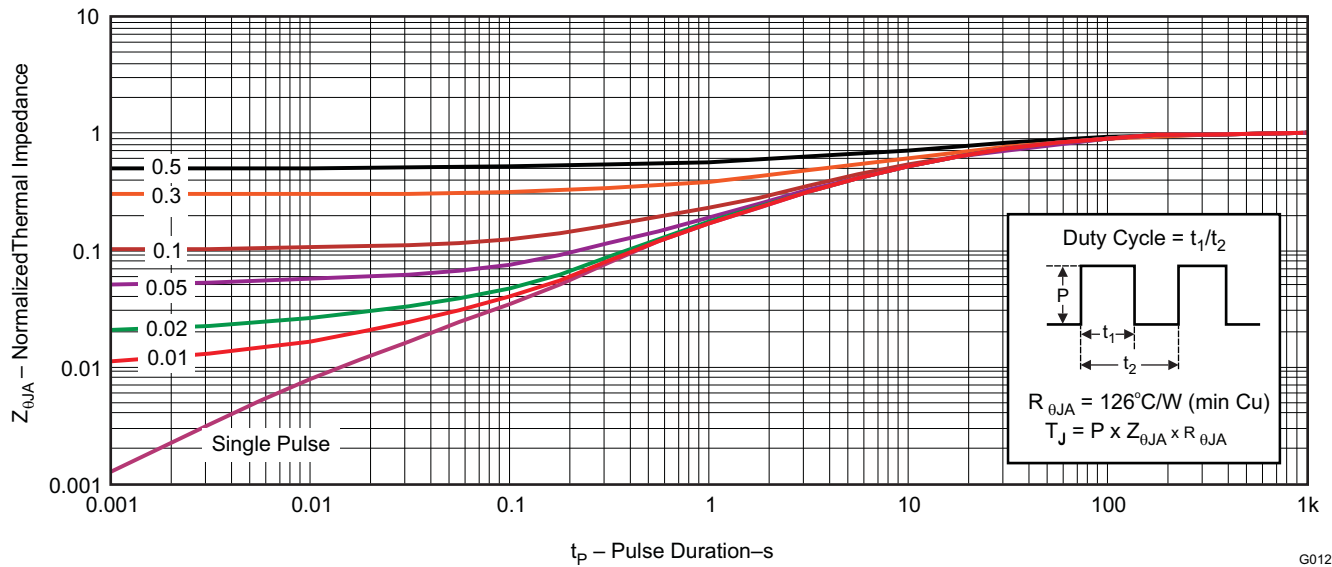


Figure 2. Transient Thermal Impedance

G012

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

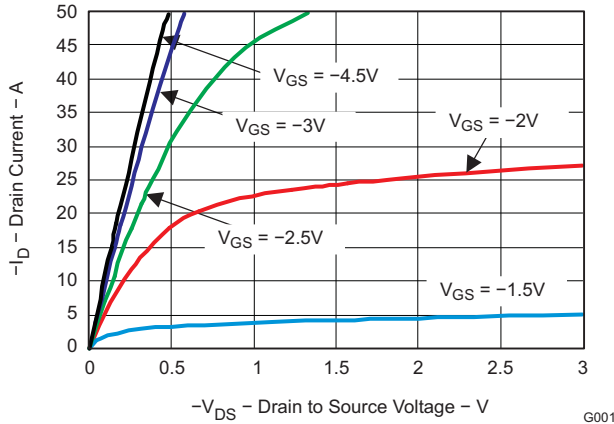


Figure 3. Saturation Characteristics

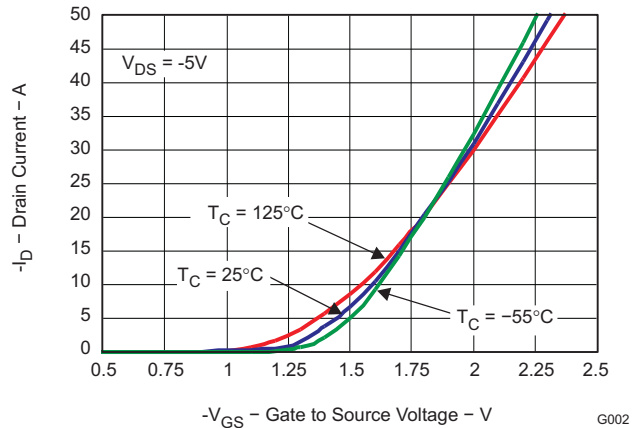


Figure 4. Transfer Characteristics

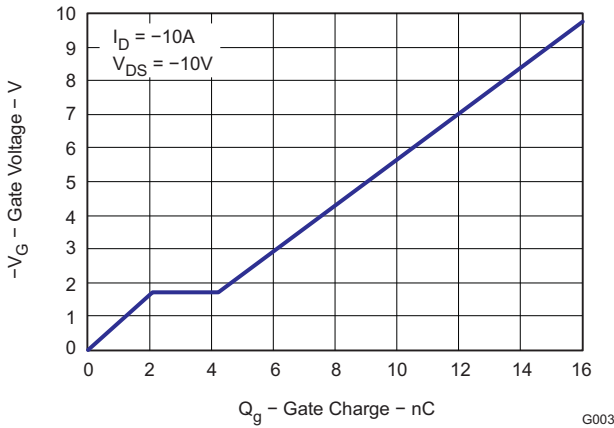


Figure 5. Gate Charge

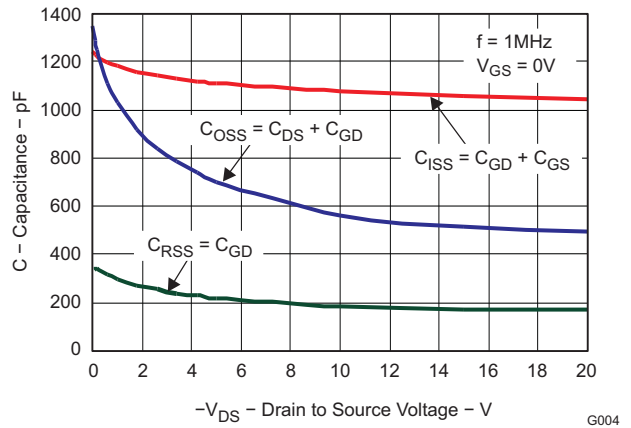


Figure 6. Capacitance

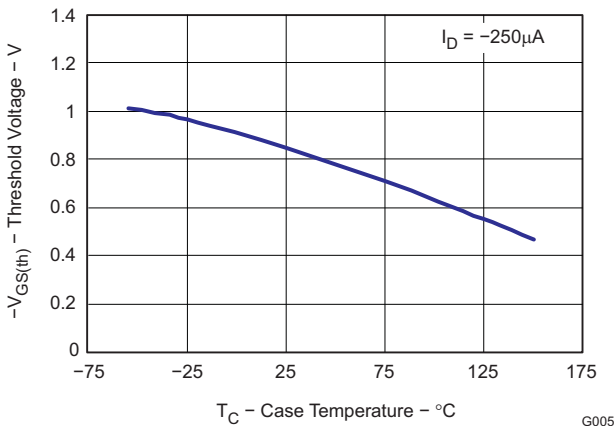


Figure 7. Threshold Voltage vs. Temperature

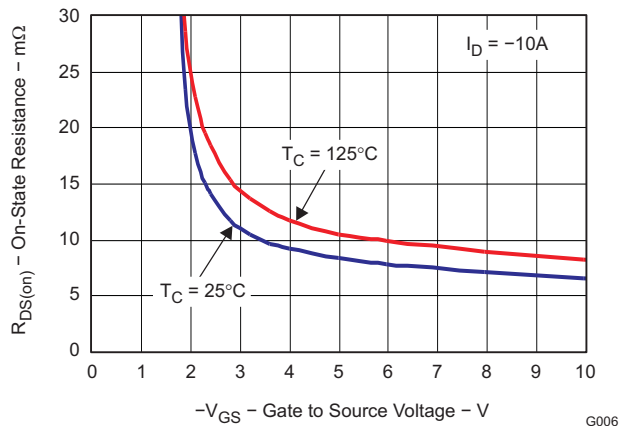


Figure 8. On Resistance vs. Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

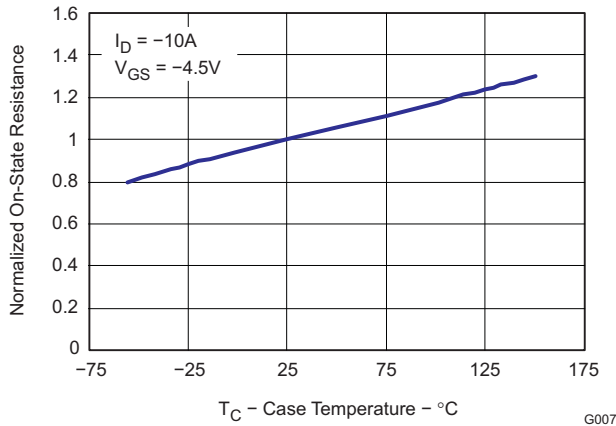


Figure 9. On Resistance vs. Temperature

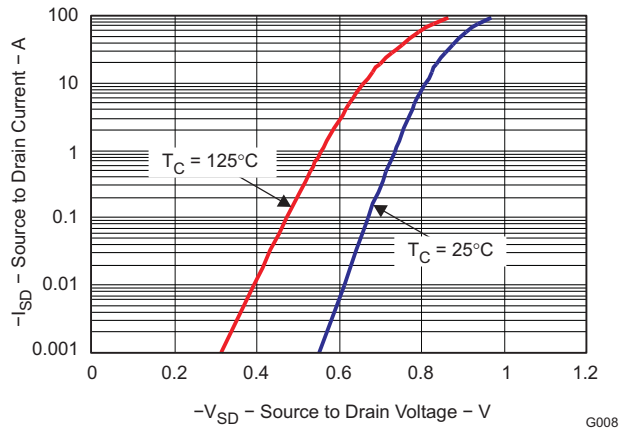


Figure 10. Typical Diode Forward Voltage

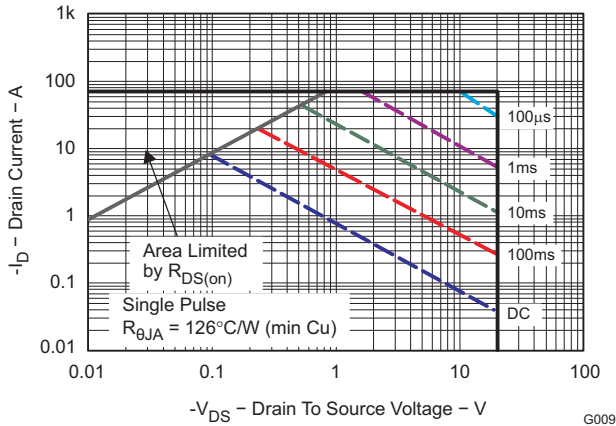


Figure 11. Maximum Safe Operating Area

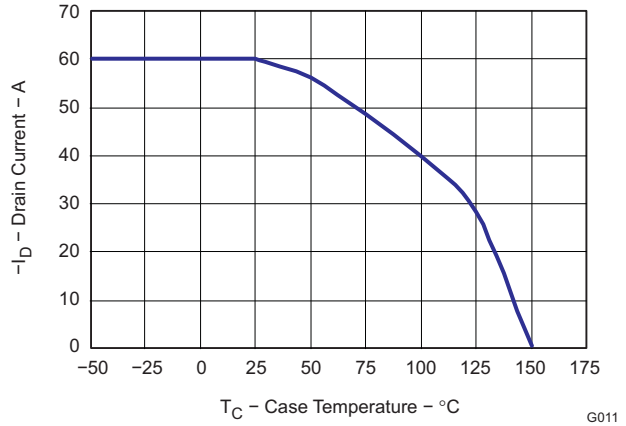
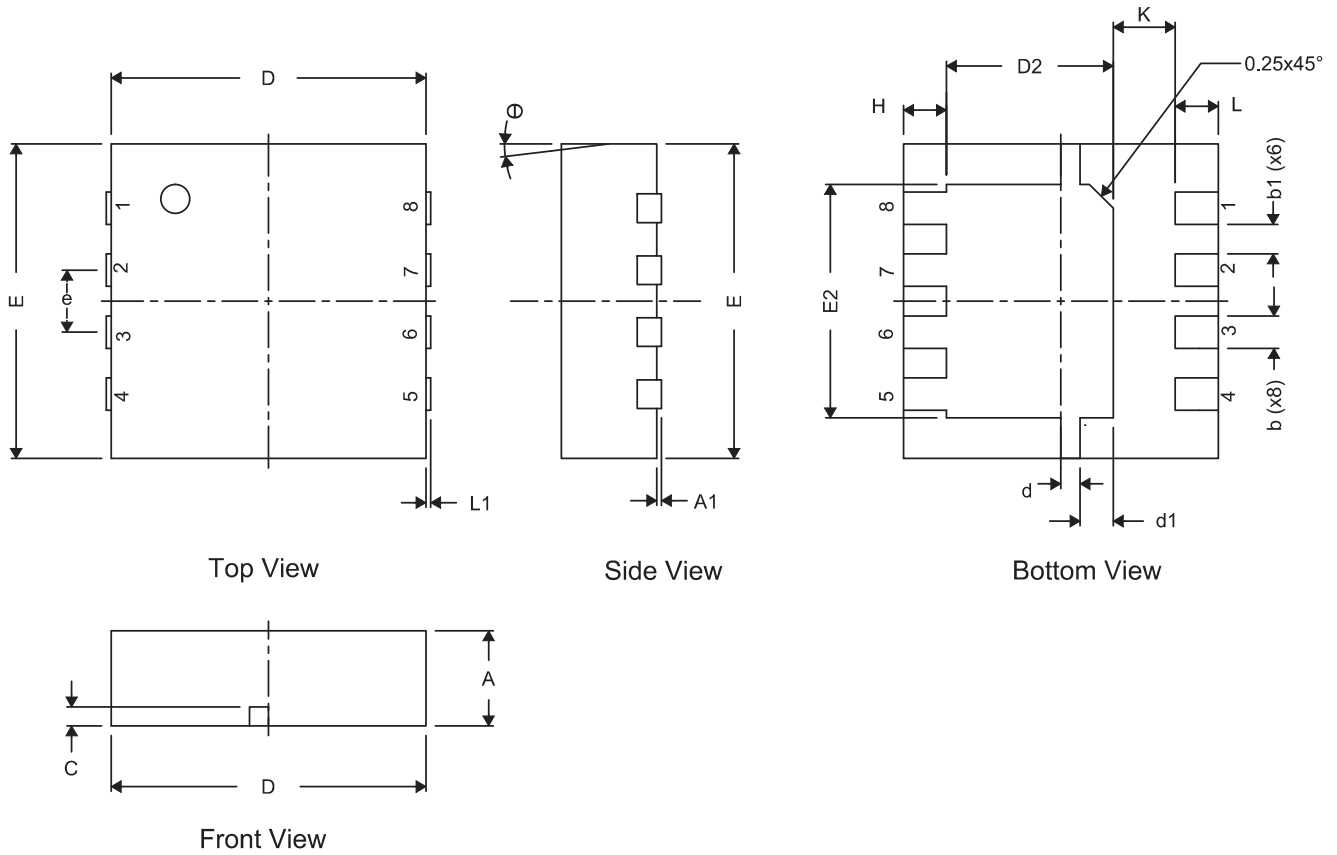


Figure 12. Maximum Drain Current vs. Temperature

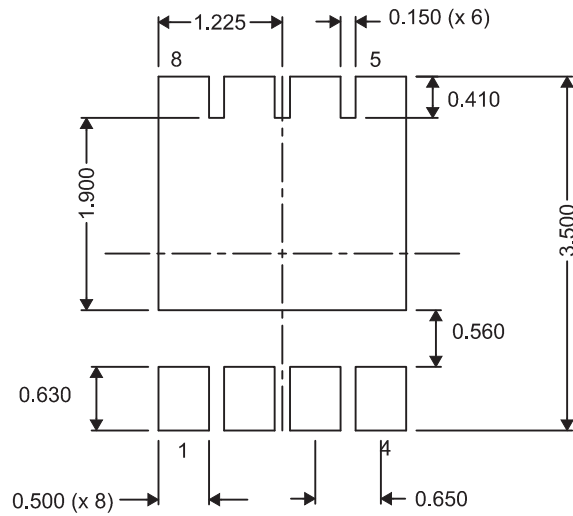
MECHANICAL DATA

CSD25401Q3 Package Dimensions

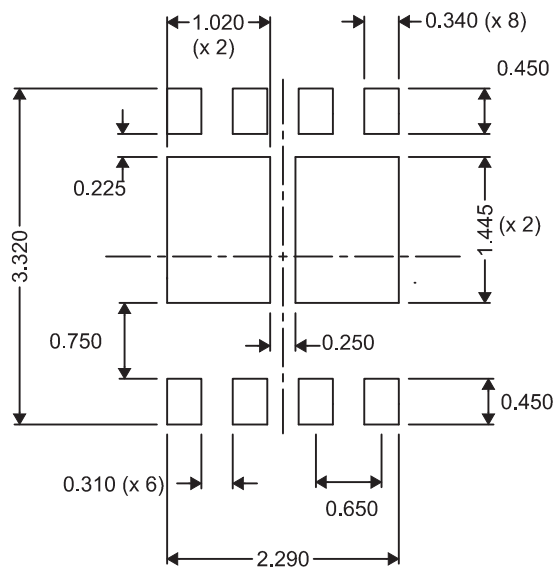


DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.950	1.000	1.100	0.037	0.039	0.043
A1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.280	0.340	0.400	0.011	0.013	0.016
b1	0.310 NOM			0.012 NOM		
c	0.150	0.200	0.250	0.006	0.008	0.010
D	3.200	3.300	3.400	0.126	0.130	0.134
D2	1.650	1.750	1.800	0.065	0.069	0.071
d	0.150	0.200	0.250	0.006	0.008	0.010
d1	0.300	0.350	0.400	0.012	0.014	0.016
E	3.200	3.300	3.400	0.126	0.130	0.134
E2	2.350	2.450	2.550	0.093	0.096	0.100
e	0.650 TYP			0.026 TYP		
H	0.35	0.450	0.550	0.014	0.018	0.022
K	0.650 TYP			0.026 TYP		
L	0.35	0.450	0.550	0.014	0.018	0.022
L1	0		0	0		0
θ	0		0	0		0

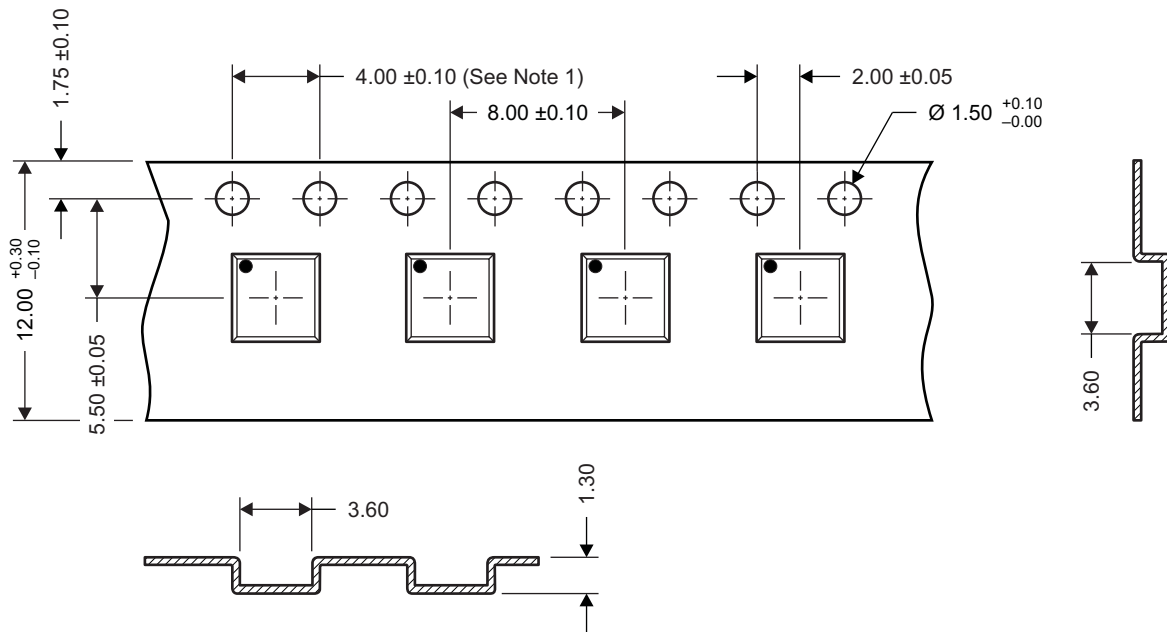
Recommended PCB Pattern



Recommended Stencil Opening



Tape and Reel Information



M0144-01

Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2
2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
3. Material: black static dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified)
5. Thickness: 0.30 ± 0.05 mm
6. MSL1 260°C (IR and Conection) PbF Reflow Compatible

REVISION HISTORY

Changes from Original (August 2009) to Revision A	Page
--	-------------

- | | |
|--|---|
| • Changed 300s to 300 μ s in Note 2 of the Abs Max Ratings table | 1 |
| • Changed Q _g Gate Charge Total (4.5V) - max value From: 2.3 To: 12.3 | 2 |

Changes from Revision A (October 2009) to Revision B	Page
---	-------------

- | | |
|---|---|
| • Deleted the Package Marking Information section | 8 |
|---|---|

Changes from Revision B (October 2010) to Revision C	Page
---	-------------

- | | |
|---|---|
| • Replaced the THERMAL CHARACTERISTICS table with the new Thermal Information Table | 2 |
| • Changed the CSD25401Q3 Package Dimensions section | 6 |
| • Changed the Recommended PCB Pattern section | 7 |

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD25401Q3	VSON-CLIP	DQG	8	2500	330.0	12.4	3.6	3.6	1.2	8.0	12.0	Q1
CSD25401Q3	VSON-CLIP	DQG	8	2500	330.0	12.8	3.6	3.6	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD25401Q3	VSON-CLIP	DQG	8	2500	336.6	336.6	41.3
CSD25401Q3	VSON-CLIP	DQG	8	2500	335.0	335.0	32.0

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